

# 10A, 50V - 600V Super Fast Rectifier

#### **FEATURES**

- AEC-Q101 qualified available
- High efficiency, low V<sub>F</sub>
- High current capability
- High reliability
- High surge current capability
- Low power loss
- UL Recognized File # E-326243
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

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- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

#### **MECHANICAL DATA**

• Case: ITO-220AB

Molding compound meets UL 94V-0 flammability rating

• Terminal: Matte tin plated leads, solderable per J-STD-002

Mounting torque: 0.56 N·m maximum
Meet JESD 201 class 2 whisker test

Polarity: As marked

• Weight: 1.70g (approximately)

KEY PARAMETERS						
PARAMETER	VALUE	UNIT				
I <sub>F</sub>	10	Α				
$V_{RRM}$	50 - 600	V				
I <sub>FSM</sub>	125	Α				
T <sub>J MAX</sub>	150	°C				
Package	ITO-220AB					
Configuration	Dual dies					

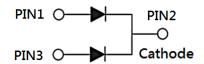








ITO-220AB



ABSOLUTE MAXIMUI		SFF	SFF	SFF	SFF	SFF	SFF	SFF	SFF	
PARAMETER	SYMBOL	_	<b>O</b>		0			1007G		UNIT
Marking code on the device		SFF	SFF	SFF	SFF	SFF	SFF	SFF	SFF	
Repetitive peak reverse voltage	$V_{RRM}$	1001G 50	1002G 100	1003G 150	1004G 200	1005G 300	1006G 400	1007G 500	1008G 600	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	105	140	210	280	350	420	V
Forward current	I <sub>F</sub>				1	0				Α
Surge peak forward current, 8.3ms single half sine wave I <sub>FSM</sub> 125 superimposed on rated load					А					
Junction temperature	TJ	-55 to +150					°C			
Storage temperature	T <sub>STG</sub>				-55 to	+150				°C

THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP	UNIT			
Junction-to-case thermal resistance	R <sub>eJC</sub>	2	°C/W			

PARAMETER	CONDITIONS	SYMBOL	TYP	MAX	UNIT	
	SFF1001G		V <sub>F</sub>	-	0.975	V
	SFF1002G					
	SFF1003G					
Convert voltage per diade <sup>(1)</sup>	SFF1004G	L				
Forward voltage per diode <sup>(1)</sup>	SFF1005G	$I_F = 5A, T_J = 25^{\circ}C$		_	1.300	V
	SFF1006G			- 	1.300	V
	SFF1007G			_	1.700	V
	SFF1008G			-	1.700	V
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>		$T_J = 25^{\circ}C$		-	10	μΑ
		T <sub>J</sub> = 125°C	l <sub>R</sub>	-	400	μA
	SFF1001G		CJ	70	-	pF
	SFF1002G					
	SFF1003G					
lunction conscitones per diade	SFF1004G	1MHz, V <sub>R</sub> = 4.0V				
Junction capacitance per diode	SFF1005G	11VII 12, V <sub>R</sub> = 4.0V				
	SFF1006G			50	_	pF
	SFF1007G			30	_	рі
	SFF1008G					
Reverse recovery time		$I_F = 0.5A$ , $I_R = 1.0A$ $I_{rr} = 0.25A$	t <sub>rr</sub>	-	35	ns

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION							
ORDERING CODE(1)(2)	PACKAGE	PACKING					
SFF10xG	ITO-220AB	50 / Tube					
SFF10xGH	ITO-220AB	50 / Tube					

## Notes:

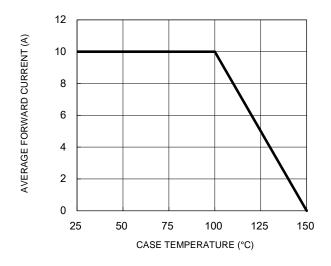
- 1. "x" defines voltage from 50V(SFF1001G) to 600V(SFF1008G)
- 2. "H" means AEC-Q101 qualified



#### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig.1 Forward Current Derating Curve



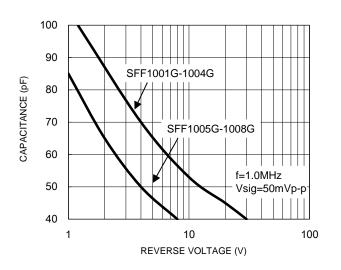
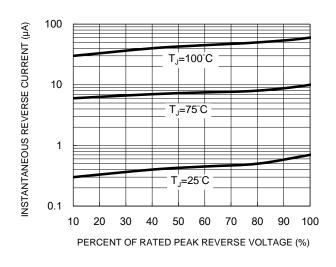


Fig.2 Typical Junction Capacitance

Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics



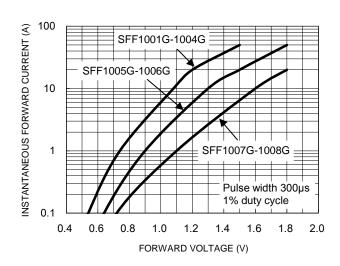
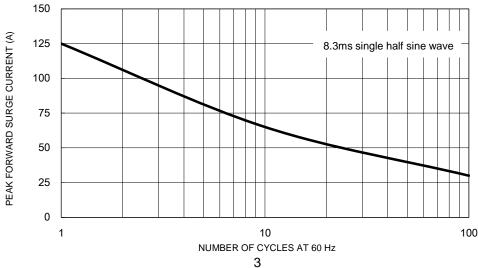


Fig.5 Maximum Non-Repetitive Forward Surge Current

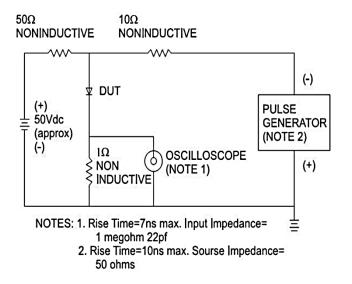


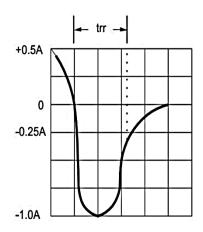


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 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram

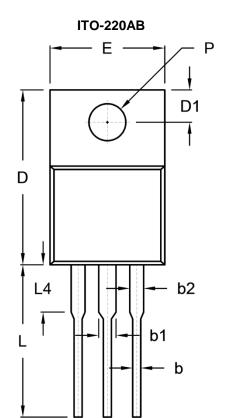




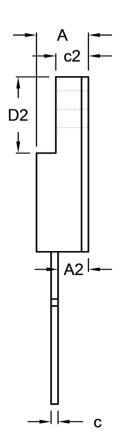




### **PACKAGE OUTLINE DIMENSIONS**



- e



DIM	Unit	(mm)	Unit (inch)		
DIM.	Min.	Max.	Min.	Max.	
Α	4.30	4.70	0.169	0.185	
A2	2.30	2.96	0.091	0.117	
b	0.50	0.90	0.020	0.035	
b1	-	1.80	-	0.071	
b2	0.95	1.45	0.037	0.057	
С	0.46	0.76	0.018	0.030	
c2	2.50	3.16	0.098	0.124	
D	14.80	15.50	0.583	0.610	
D1	2.40	3.20	0.094	0.126	
D2	6.30	6.90	0.248	0.272	
E	9.60	10.30	0.378	0.406	
е	2.41	2.67	0.095	0.105	
L	12.60	13.80	0.496	0.543	
L4	-	4.10	-	0.161	
Р	3.00	3.40	0.118	0.134	

#### **MARKING DIAGRAM**



P/N = Marking Code G = Green Compound

YWW = Date Code F = Factory Code



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